ShiLing®

ZHEJIANG SHILING SEMICONDUCTOR CO.,LTD.

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Specifcation of products

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SYMBOL	CHARACTERISTIC	TEST CONDI TIONS	T_j (℃)	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean for ward current	180° half sine wave 50Hz Single side cooled,T_C=100°C	150			250	A
$I_{F(RMS)}$	RMS for ward current	Single side cooled,T_C=100°C	150			393	A
V_{RRM}	Repetitive peak reverse voltage	V_{RRM} tp=10ms V_{RsM}= V_{DRM}					

OUTLINE DR AWING & CIRCUIT DIAGRAM

Rating and Characteristic

Fig. 1

Fig. 2

Fig. 3

Fig. 4

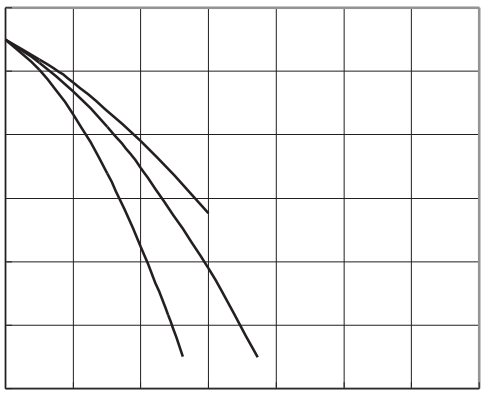


Fig. 5

Fig. 6

Outside Dimension



